

IXTA110N055T Datasheet



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DiGi Electronics Part Number IXTA110N055T-DG

Manufacturer IXYS

Manufacturer Product Number IXTA110N055T

Description MOSFET N-CH 55V 110A TO263

Detailed Description N-Channel 55 V 110A (Tc) 230W (Tc) Surface Mount

TO-263AA



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTA110N055T	IXYS
Series:	Product Status:
TrenchMV™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
55 V	110A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	7m0hm @ 25A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4V @ 100μA	67 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	3080 pF @ 25 V
FET Feature:	Power Dissipation (Max):
-	230W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 175°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
TO-263AA	TO-263-3, D2PAK (2 Leads + Tab), TO-263AB
Base Product Number:	
IXTA110	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095



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